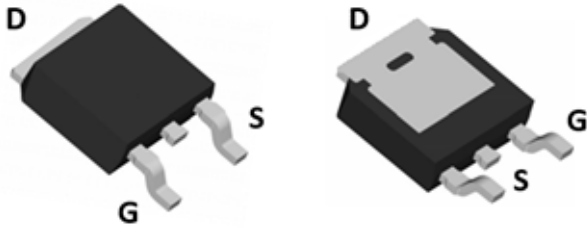
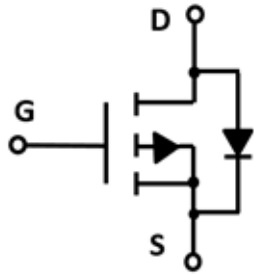


P-Channel Enhancement Mode Field Effect Transistor



TO-252



Product Summary

- V_{DS} -100V
- I_D -18A
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) <90 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) <110 mohm
- 100% UIS Tested
- 100% ∇V_{DS} Tested

General Description

- Split gate trench MOSFET technology
- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity

Applications

- Power management
- Portable equipment

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	-100	V
Gate-source Voltage		V_{GS}	± 20	V
Drain Current	$T_C=25^\circ C$	I_D	-18	A
	$T_C=100^\circ C$		-12	
Pulsed Drain Current ^A		I_{DM}	-72	A
Avalanche energy ^B		E_{AS}	100	mJ
Total Power Dissipation	$T_C=25^\circ C$	P_D	72	W
	$T_C=100^\circ C$		28.8	
Junction and Storage Temperature Range		T_J, T_{STG}	-55~+150	$^\circ C$

■ Thermal resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient ^D	$t \leq 10S$	$R_{\theta JA}$	15	20	$^\circ C/W$
Thermal Resistance Junction-to-Ambient ^D	Steady-State		40	50	
Thermal Resistance Junction-to-Case	Steady-State	$R_{\theta JC}$	1.35	1.7	

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJD18GP10A	F1	YJD18GP10A	2500	2500	250000	13" reel



YJD18GP10A

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250μA	-100			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V, V _{GS} =0V	T _J =25°C		-1	μA
			T _J =55°C		-5	
			T _J =125°C		-10	
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} =0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =-250μA	-1.0	-1.8	-2.5	V
Static Drain-Source On-Resistance	R _{DS(on)}	V _{GS} = -10V, I _D =-10A		75	90	mΩ
		V _{GS} = -4.5V, I _D =-5A		85	110	
Diode Forward Voltage	V _{SD}	I _S =-10A, V _{GS} =0V			-1.3	V
Maximum Body-Diode Continuous Current	I _S				-18	A
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{DS} =-50V, V _{GS} =0V, f=1MHz		1051		pF
Output Capacitance	C _{oss}			119		
Reverse Transfer Capacitance	C _{rss}			25		
Switching Parameters						
Total Gate Charge	Q _{g(-10V)}	V _{GS} =-10V, V _{DS} =-50V, I _D =-5A		20.1		nC
Total Gate Charge	Q _{g(-4.5V)}			9.7		
Gate-Source Charge	Q _{gs}			3.9		
Gate-Drain Charge	Q _{gd}			4.3		
Reverse Recovery Charge	Q _{rr}	I _F =-5A, di/dt=100A/us		140		nC
Reverse Recovery Time	t _{rr}			70		
Turn-on Delay Time	t _{D(on)}	V _{GS} =-10V, V _{DD} =-50V, R _L =2.5Ω R _{GEN} =6Ω		10		ns
Turn-on Rise Time	t _r			30		
Turn-off Delay Time	t _{D(off)}			77		
Turn-off fall Time	t _f			81		

A. Repetitive rating; pulse width limited by max. junction temperature.

B. V_{DD}=50V, R_G=25Ω, L=0.5mH.

C. Pd is based on max. junction temperature, using junction-case thermal resistance.

D. The value of RθJA is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with TA =25° C. The Power dissipation PDSM is based on RθJA ≤ 10s and the maximum allowed junction temperature of 150° C. The value in any given application depends on the user's specific board design.



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■ Typical Performance Characteristics

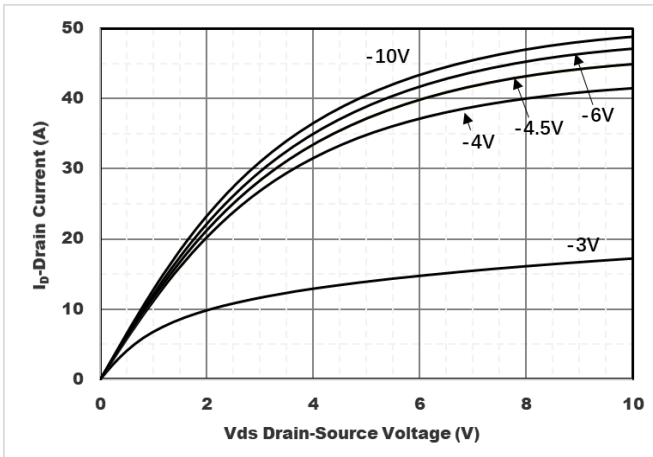


Figure1. Output Characteristics

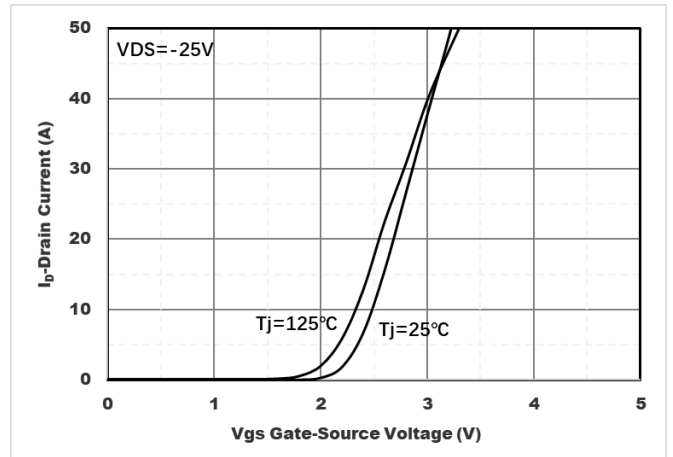


Figure2. Transfer Characteristics

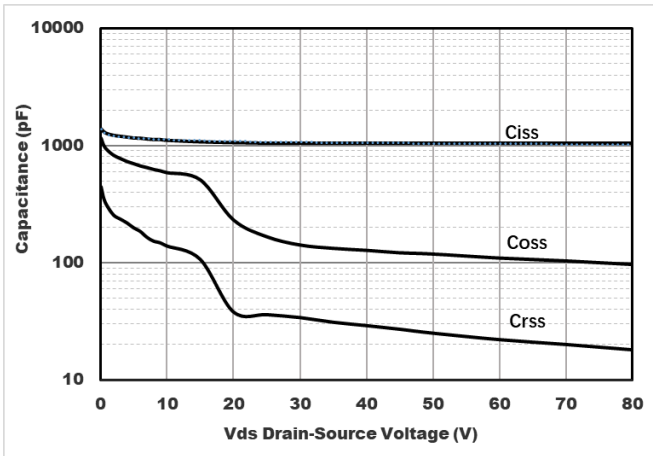


Figure3. Capacitance Characteristics

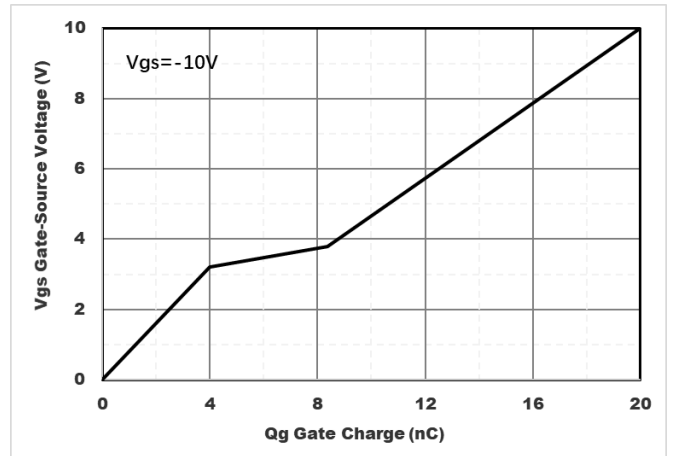


Figure4. Gate Charge

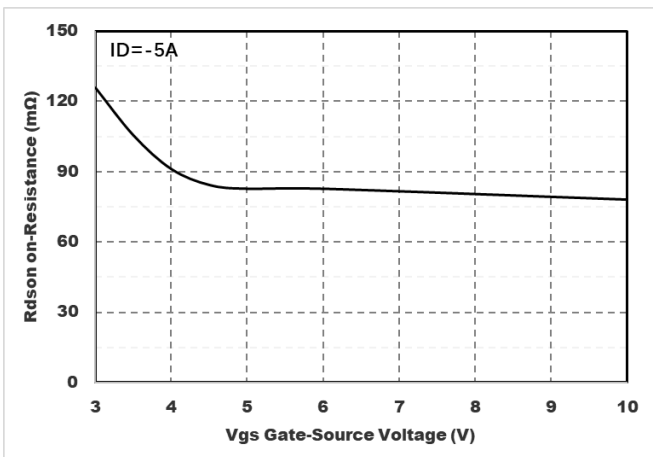


Figure5. : On-Resistance vs. Gate to Source Voltage

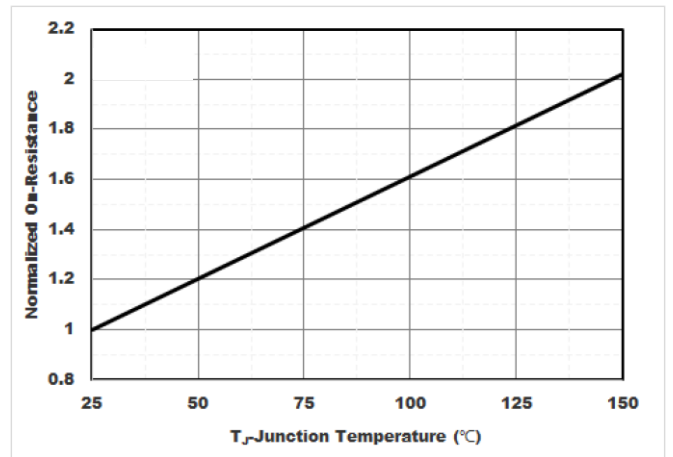


Figure6. Normalized On-Resistance



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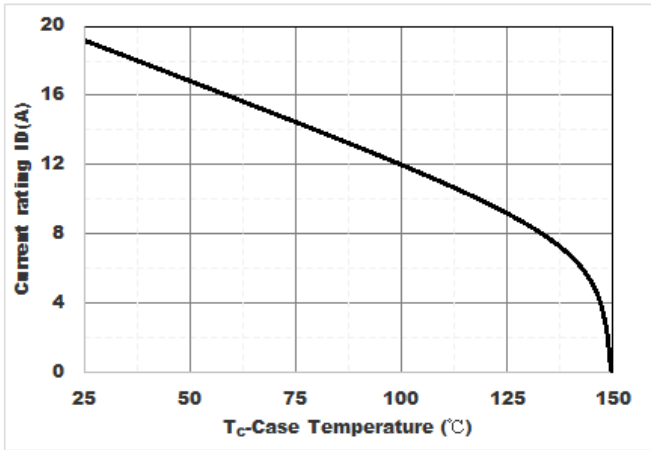


Figure7. Drain current

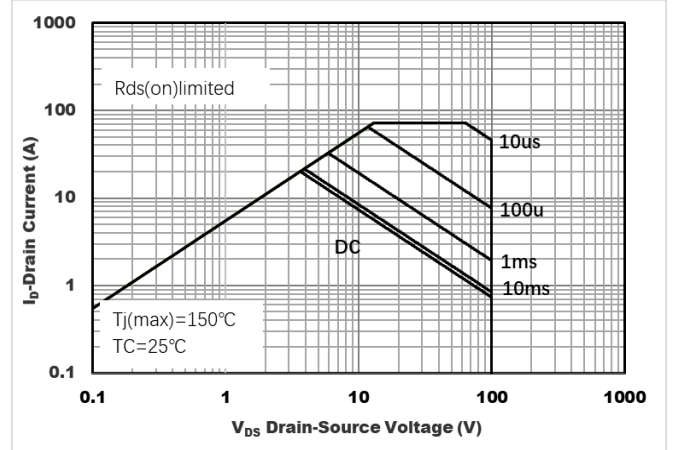


Figure8.Safe Operation Area

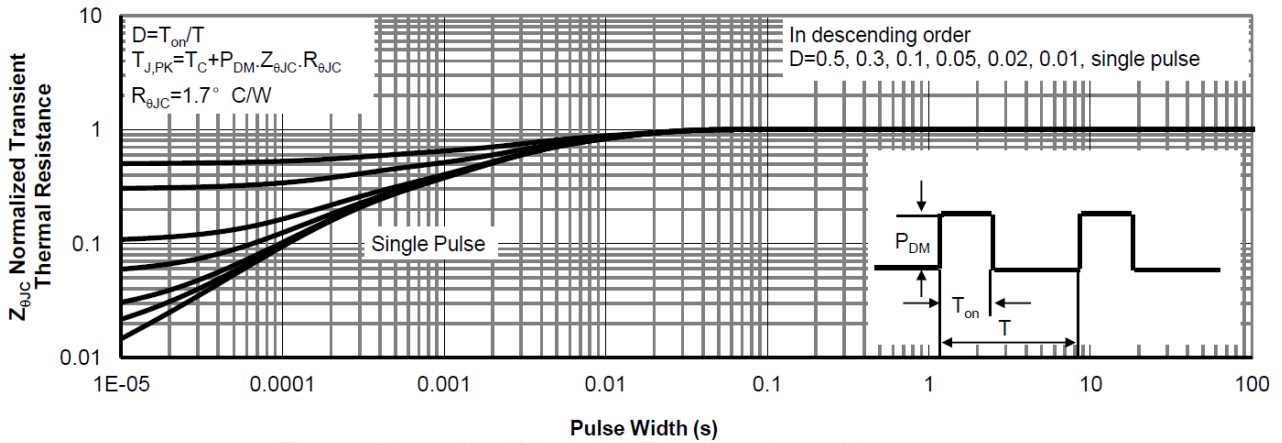
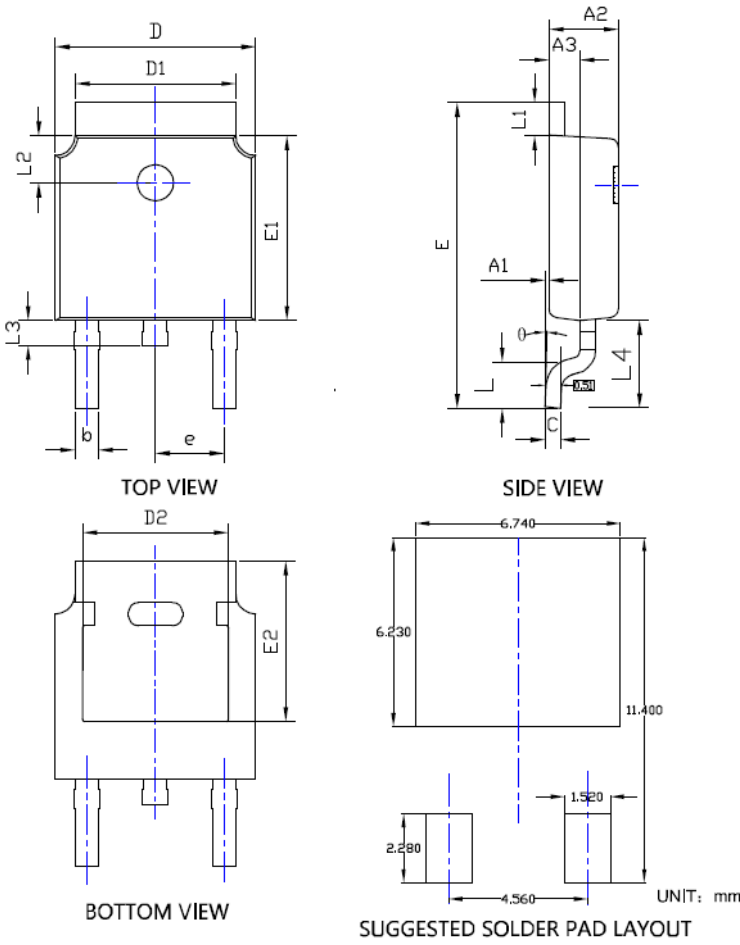


Figure9.Normalized Maximum Transient thermal impedance



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■ TO-252 Package information



SYMBOL	DIMENSIONS					
	INCHES			Millimeter		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A1	0,000	---	0,008	0,000	---	0,200
A2	0,087	0,091	0,094	2,200	2,300	2,400
A3	0,035	0,039	0,043	0,900	1,000	1,100
b	0,026	0,030	0,034	0,660	0,760	0,860
c	0,018	0,020	0,023	0,460	0,520	0,580
D	0,256	0,260	0,264	6,500	6,600	6,700
D1	0,203	0,209	0,215	5,150	5,300	5,450
D2	0,181	0,189	0,195	4,600	4,800	4,950
E	0,390	0,398	0,406	9,900	10,100	10,300
E1	0,236	0,240	0,244	6,000	6,100	6,200
E2	0,203	0,209	0,215	5,150	5,300	5,450
e	0,090BSC			2,286BSC		
L	0,049	0,059	0,069	1,250	1,500	1,750
L1	0,035	---	0,050	0,900	---	1,270
L2	0,055	---	0,075	1,400	---	1,900
L3	0,240	0,310	0,039	0,600	0,800	1,000
L4	0,114REF			2,900REF		
0	0°	---	10°	0°	---	10°



YJD18GP10A

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